

WP34SF4BT

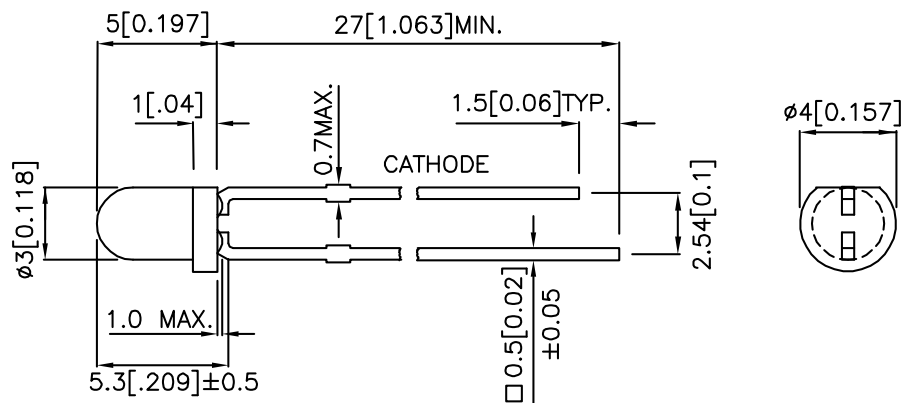
Features

- MECHANICALLY AND SPECTRALLY MATCHED TO THE WP32P3C PHOTOTRANSISTOR.
- BLUE TRANSPARENT LENS.
- RoHS COMPLIANT.

Description

SF4 Made with Gallium Aluminum Arsenide Infrared Emitting diodes.

Package Dimensions



Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is $\pm 0.25 (0.01")$ unless otherwise noted.
3. Lead spacing is measured where the leads emerge from the package.
4. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Po (mW/sr) @ 20mA*50mA		Viewing Angle
			Min.	Typ.	2θ1/2
WP34SF4BT	GaAlAs	BLUE TRANSPARENT	1.6	4	50°
			*7	*20	50°

Notes:

1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.

2.* Luminous intensity with asterisk is measured at 50mA.

Electrical / Optical Characteristics at TA=25°C

Item	P/N	Symbol	Typ.	Max.	Units	Test Conditions
Forward Voltage	SF4	VF	1.3	1.6	V	IF=20mA
Reverse Current	SF4	IR	-	10	uA	VR=5V
Capacitance	SF4	C	90	-	pF	VF=0V;f=1MHz
Peak Spectral Wavelength	SF4	λP	880	-	nm	IF=20mA
Spectral Bandwidth	SF4	Δλ1/2	50	-	nm	IF=20mA

Absolute Maximum Ratings at TA=25°C

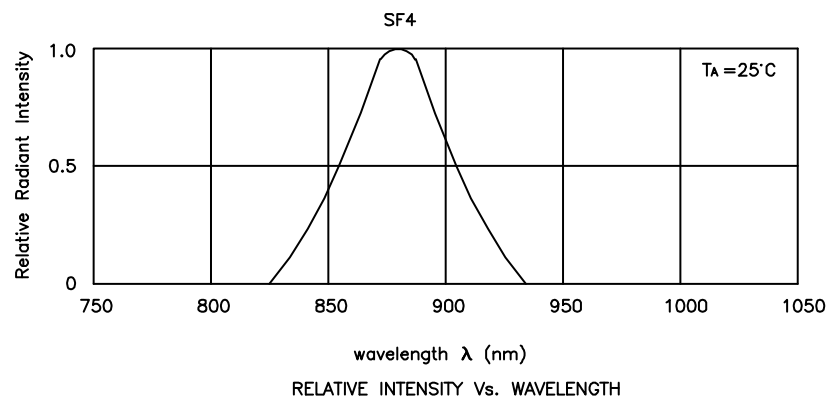
Parameter	Symbol	SF4	Units
Power Dissipation	PT	100	mW
DC Forward Current	IF	50	mA
Peak Forward Current[1]	iFS	1.2	A
Reverse Voltage	VR	5	V
Operating Temperature	TA	-40 To +85	°C
Storage Temperature	TSTG	-40 To +85	°C
Lead Solder Temperature [2]	260°C For 3 Seconds		
Lead Solder Temperature [3]	260°C For 5 Seconds		

Notes:

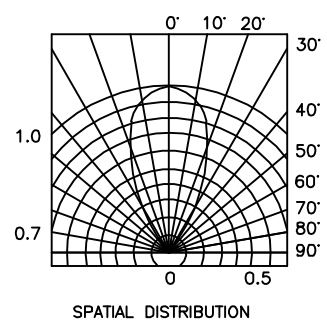
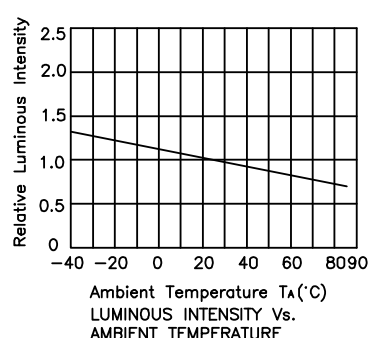
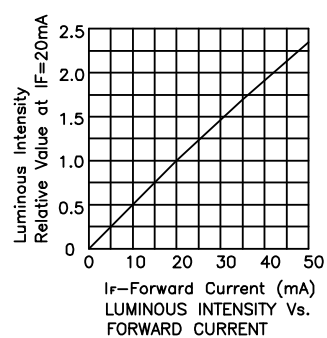
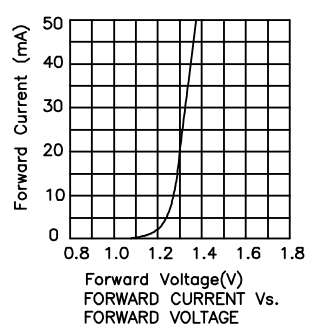
1. 1/100 Duty Cycle, 10us Pulse Width.

2. 2mm below package base.

3. 5mm below package base.

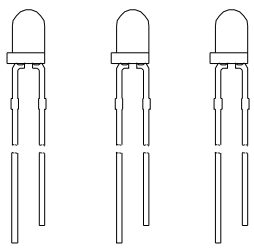


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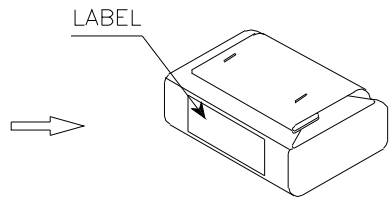


PACKING & LABEL SPECIFICATIONS

WP34SF4BT



P/N: WP34XXX

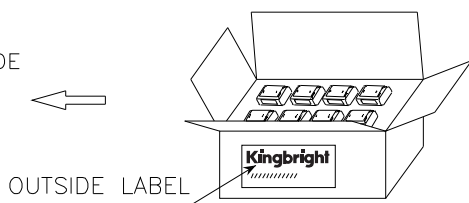


1,000PCS / BAG



56K / 9# BOX

OUTSIDE LABEL



OUTSIDE LABEL

28K / 5# BOX

Kingbright	
Q.C.	
TYPE NO : WP34XXX	QC xxx xx xxx PASSED
QUANTITY : 1,000 pcs	Date
S/N : XXX	CODE: XX
LOT NO : 	RoHS Compliant

Remarks:

If special sorting is required (e.g. binning based on forward voltage or radiant intensity), the typical accuracy of the sorting process is as follows:

1. Radiant Intensity: +/-15%
2. Forward Voltage: +/-0.1V

Note: Accuracy may depend on the sorting parameters.